

# 2SD842

SILICON NPN TRIPLE DIFFUSED TYPE  
(DARLINGTON POWER)

HIGH CURRENT SWITCHING APPLICATIONS.

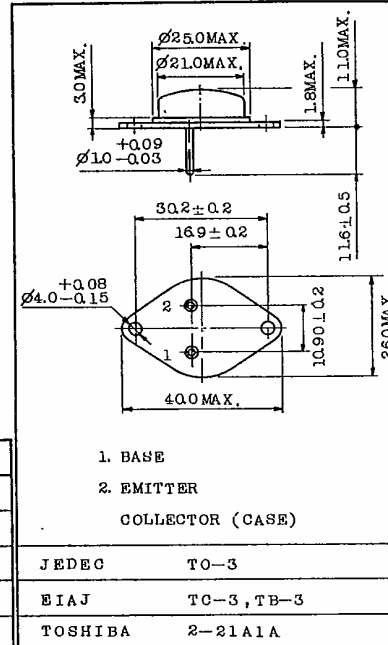
**FEATURES:**

- . High Collector Current :  $I_C = 30A$
- . High DC Current Gain  
:  $h_{FE}=1000$  (Min.), ( $V_{CE}=5V, I_C=20A$ )
- . Monolithic Construction with Built-In Base-Emitter Shunt Resistor.

**MAXIMUM RATINGS ( $T_a=25^\circ C$ )**

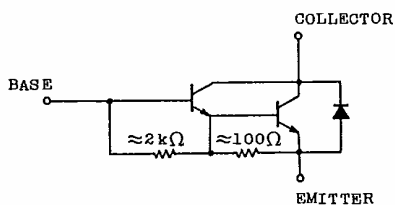
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	80	V
Collector-Emitter Voltage	$V_{CEO}$	80	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	30	A
Base Current	$I_B$	1	A
Collector Power Dissipation ( $T_c=25^\circ C$ )	$P_C$	150	W
Junction Temperature	$T_j$	150	$^\circ C$
Storage Temperature Range	$T_{stg}$	-65 ~ 150	$^\circ C$

Unit in mm



Mounting kit No. AC73  
Weight : 12.9g

**EQUIVALENT CIRCUIT**

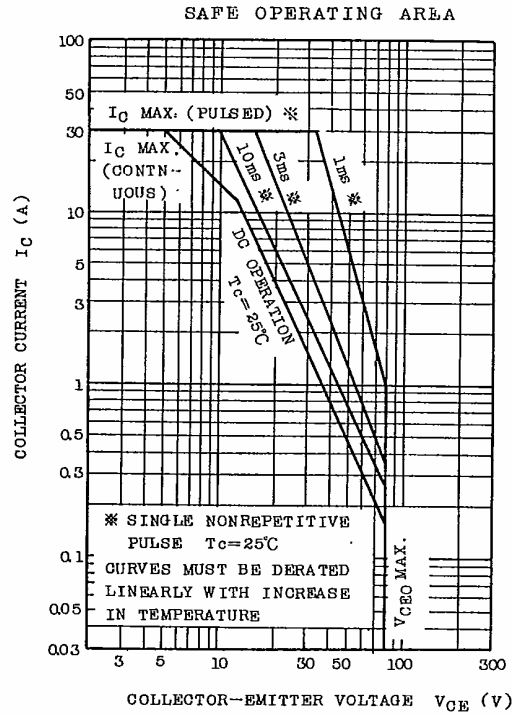
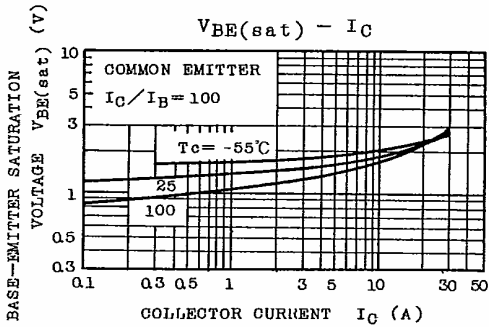
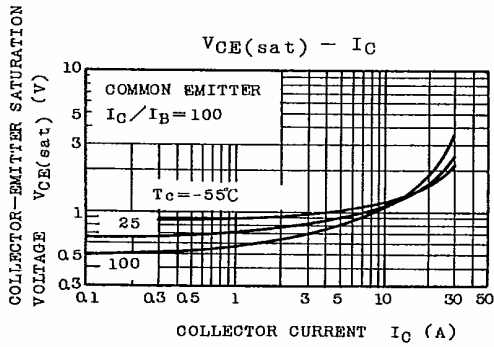
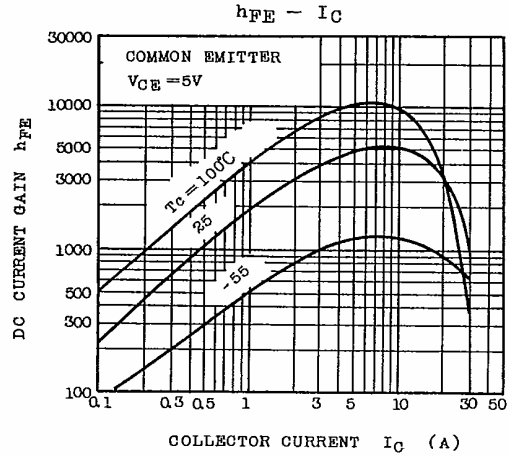
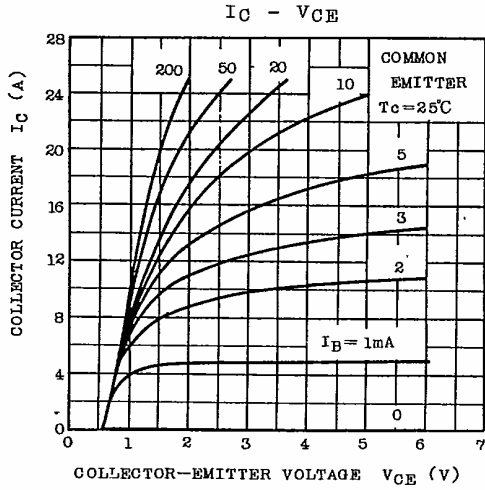


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ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		ICBO	V <sub>CB</sub> =80V, I <sub>E</sub> =0	-	-	100	μA
Emitter Cut-off Current		IEBO	V <sub>EB</sub> =5V, I <sub>C</sub> =0	-	-	10	mA
Collector-Emitter Breakdown Voltage		V(BR)CEO	I <sub>C</sub> =50mA, I <sub>B</sub> =0	80	-	-	V
DC Current Gain		hFE(1)	V <sub>CE</sub> =5V, I <sub>C</sub> =20A	1000	-	-	
		hFE(2)	V <sub>CE</sub> =5V, I <sub>C</sub> =30A	200	-	-	
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	I <sub>C</sub> =20A, I <sub>B</sub> =0.2A	-	-	3	V
Base-Emitter Saturation Voltage		V <sub>BE(sat)</sub>		-	-	3.5	V
Emitter-Collector Forward Voltage		V <sub>ECF</sub>	I <sub>E</sub> =10A, I <sub>B</sub> =0	-	-	3	V
Transition Frequency		f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =1A	-	14	-	MHz
Collector Output Capacitance		C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz	-	280	-	pF
Switching Time	Turn-on Time	t <sub>on</sub>	<p> <math>V_{CC}=50V</math>  <math>R=10\Omega</math>  <math>I_{B1} = -I_{B2} = 0.01A</math>  <math>DUTY\ CYCLE \leq 1\%</math> </p>	-	0.7	-	μs
	Storage Time	t <sub>stg</sub>		-	8	-	
	Fall Time	t <sub>f</sub>		-	2.5	-	

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